



# AZ100LVEL16VT ARIZONA MICROTEK, INC.

## ECL/PECL Oscillator Gain Stage & Buffer with Selectable Enable

### FEATURES

- High Bandwidth for  $\geq 1\text{GHz}$
- **Similar Operation as AZ100LVEL16VR**  
**Except in Disabled Condition:  $Q_{HG}$  is High**
- Operating Range of 3.0V to 5.5V
- Minimizes External Components
- Selectable Enable Polarity and Threshold (CMOS/TTL or PECL)
- Available in a 3x3 mm or 2x2 mm MLP Package

### PACKAGE AVAILABILITY

PACKAGE	PART NO.	MARKING
MLP 8 (2x2x.9)	AZ100LVEL16VTMA	TMA
MLP 8 (2x2x.9)	AZ100LVEL16VTMAR1	TMA
MLP 8 (2x2x.75)	AZ100LVEL16VTNA	TNA
MLP 8 (2x2x.75)	AZ100LVEL16VTNAR1	TNA
MLP 8 (2x2x.9)	AZ100LVEL16VTMB	TMB
MLP 8 (2x2x.9)	AZ100LVEL16VTMBR1	TMB
MLP 8 (2x2x.75)	AZ100LVEL16VTNB	TNB
MLP 8 (2x2x.75)	AZ100LVEL16VTNBR1	TNB
MLP 16	AZ100LVEL16VTL	AZM16T
MLP 16 T&R	AZ100LVEL16VTLR1	AZM16T
MLP 16 T&R	AZ100LVEL16VTLR2	AZM16T
DIE	AZ100LVEL16VTX	N/A

### DESCRIPTION

The AZ100LVEL16VT is a specialized oscillator gain stage with high gain output buffer including an enable. The  $Q_{HG}/\bar{Q}_{HG}$  outputs have a voltage gain several times greater than the  $Q/\bar{Q}$  outputs.

#### MLP 16, 3x3 mm Package (L) or DIE (X)

The AZ100LVEL16VTL provides a selectable enable that allows continuous oscillator operation. See truth table below for enable function. If Enable pull-up is desired in the CMOS mode, an external  $\leq 20\text{ k}\Omega$  resistor connecting EN to  $V_{CC}$  will override the on-chip pull-down resistor. When disabled the  $Q_{HG}$  output is forced high and the  $\bar{Q}_{HG}$  output is forced low. The AZ100LVEL16VT also provides a  $V_{BB}$  and  $470\ \Omega$  internal bias resistors from D to  $V_{BB}$  and  $\bar{D}$  to  $V_{BB}$ . The  $V_{BB}$  pin can support 1.5 mA sink/source current. Bypassing  $V_{BB}$  to ground with a  $0.01\ \mu\text{F}$  capacitor is recommended.

The outputs Q and  $\bar{Q}$  each have a selectable on-chip pull-down current source. See truth table below for current source functions. External resistors may also be used to increase pull-down current to a maximum total of 25 mA.

Outputs  $Q_{HG}$  and  $\bar{Q}_{HG}$  each have an optional on-chip pull-down current source of 10 mA. When pad/pin  $V_{EEP}$  is left open (NC), the output current sources are disabled and the  $Q_{HG}/\bar{Q}_{HG}$  operate as standard PECL/ECL. When  $V_{EEP}$  is connected to  $V_{EE}$ , the current sources are activated. The  $Q_{HG}/\bar{Q}_{HG}$  pull-down current can be decreased, by using a resistor to connect  $V_{EEP}$  to  $V_{EE}$ . (See graph on page 5)

#### MLP 8, 2x2 mm Package (M,N) with A & B Bonding Options

The MLP 8, 2x2mm versions of the AZ100LVEL16VT operate in the PECL/ECL mode with an enable input (EN) controlling the  $Q_{HG}/\bar{Q}_{HG}$  outputs. When the EN input is LOW, the  $\bar{Q}$  and  $Q_{HG}/\bar{Q}_{HG}$  outputs follow the input. When EN is HIGH, the  $Q_{HG}$  output is forced high and the  $\bar{Q}_{HG}$  output is forced low.

The Q,  $Q_{HG}$ , and  $\bar{Q}_{HG}$  current sources are disabled, while the  $\bar{Q}$  output operates with a 4 mA current source to  $V_{EE}$ . This is accomplished by internal bonding of CS-SEL, EN-SEL and  $V_{EEP}$ .

For the MLP 8, 2x2mm version B, the  $\bar{D}$  input is internally tied directly to the  $V_{BB}$  pin and the D input is tied to the  $V_{BB}$  pin through a  $470\ \Omega$  internal bias resistor. In the MLP 8, 2x2mm version A, both D and  $\bar{D}$  inputs are brought out and tied to the  $V_{BB}$  pin through  $470\ \Omega$  internal bias resistors.

NOTE: Specifications in the ECL/PECL tables are valid when thermal equilibrium is established.

# AZ100LVEL16VT

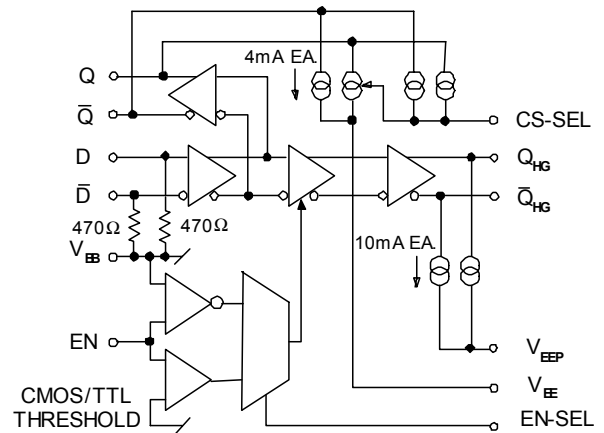
## ENABLE TRUTH TABLE

EN-SEL (MLP 16 or DIE)	EN	Q/ $\bar{Q}$	Q <sub>HG</sub>	$\bar{Q}$ <sub>HG</sub>
NC	PECL Low, V <sub>EE</sub> or NC	Data	Data	Data
NC	PECL High or V <sub>CC</sub>	Data	High	Low
V <sub>EE</sub> *	CMOS Low or V <sub>EE</sub>	Data	High	Low
V <sub>EE</sub> *	CMOS High or V <sub>CC</sub>	Data	Data	Data
V <sub>EE</sub> *	NC, no external pull-up	Data	High	Low
V <sub>EE</sub> *	NC, with $\leq 20k\Omega$ to V <sub>CC</sub>	Data	Data	Data

\*Connections to V<sub>CC</sub> or V<sub>EE</sub> must be less than 1 $\Omega$ .

## PIN DESCRIPTION

PIN	FUNCTION
D/ $\bar{D}$	Data Inputs
Q/ $\bar{Q}$	Data Outputs
Q <sub>HG</sub> / $\bar{Q}$ <sub>HG</sub>	Data Outputs w/High Gain
V <sub>BB</sub>	Reference Voltage Output
EN-SEL	Selects Enable Logic
EN	Enable Input
CS-SEL	Selects Q and $\bar{Q}$ Current Source Magnitude
V <sub>EHP</sub>	Optional Q <sub>HG</sub> and $\bar{Q}$ <sub>HG</sub> Current Sources
V <sub>EE</sub>	Negative Supply
V <sub>CC</sub>	Positive Supply



MLP16

## CURRENT SOURCE TRUTH TABLE (MLP 16 or DIE)

CS-SEL	Q	$\bar{Q}$
NC	4mA typ.	4mA typ.
V <sub>EE</sub> *	8mA typ.	8mA typ.
V <sub>CC</sub> *	0	4mA typ.

\*Connections to V<sub>CC</sub> or V<sub>EE</sub> must be less than 1 $\Omega$ .

**Absolute Maximum Ratings are those values beyond which device life may be impaired.**

Symbol	Characteristic	Rating	Unit
V <sub>CC</sub>	PECL Power Supply (V <sub>EE</sub> = 0V)	0 to +8.0	Vdc
V <sub>I</sub>	PECL Input Voltage (V <sub>EE</sub> = 0V)	0 to +6.0	Vdc
V <sub>EE</sub>	ECL Power Supply (V <sub>CC</sub> = 0V)	-8.0 to 0	Vdc
V <sub>I</sub>	ECL Input Voltage (V <sub>CC</sub> = 0V)	-6.0 to 0	Vdc
I <sub>OUT</sub>	Output Current Q <sub>HG</sub> / $\bar{Q}$ <sub>HG</sub> --- Continuous	50	mA
	--- Surge	100	
	Output Current Q/ $\bar{Q}$ --- Continuous	25	
	--- Surge	50	
T <sub>A</sub>	Operating Temperature Range	-40 to +85	$^{\circ}$ C
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	$^{\circ}$ C

# AZ100LVEL16VT

## 100K ECL DC Characteristics ( $V_{EE} = -3.0V$ to $-5.5V$ , $V_{CC} = GND$ )

Symbol	Characteristic	-40°C		0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
$V_{OH}$	Output HIGH Voltage <sup>2</sup>	-1045	-835	-995	-835	-995	-835	-995	-835	mV
$V_{OH}$	Output HIGH Voltage <sup>4</sup>	-1085	-880	-1025	-880	-1025	-880	-1025	-880	mV
$V_{OL}$	Output LOW Voltage <sup>2,4</sup>	-1925	-1555	-1900	-1620	-1900	-1620	-1900	-1620	mV
$V_{IH}$	Input HIGH Voltage									
	D/D, EN (PECL) EN (CMOS/TTL)	-1165 $V_{EE}+2000$	-880 $V_{CC}$	-1165 $V_{EE}+2000$	-880 $V_{CC}$	-1165 $V_{EE}+2000$	-880 $V_{CC}$	-1165 $V_{EE}+2000$	-880 $V_{CC}$	mV
$V_{IL}$	Input LOW Voltage									
	D/D, EN (PECL) EN (CMOS/TTL)	-1810 $V_{EE}$	-1475 $V_{EE} + 800$	-1810 $V_{EE}$	-1475 $V_{EE} + 800$	-1810 $V_{EE}$	-1475 $V_{EE} + 800$	-1810 $V_{EE}$	-1475 $V_{EE} + 800$	mV
$V_{BB}$	Reference Voltage	-1390	-1250	-1390	-1250	-1390	-1250	-1390	-1250	mV
$I_{IL}$	Input LOW Current EN <sup>3</sup>	0.5		0.5		0.5		0.5		μA
$I_{IH}$	Input HIGH Current EN <sup>3</sup>		150		150		150		150	μA
$I_{EE}$	Power Supply Current <sup>1</sup>		48		48		48		54	mA

1. Specified with  $V_{EEP}$  and CS-SEL open for MLP16 and DIE. Subtract 4mA for MLP8.
2. Specified with  $V_{EEP}$  and CS-SEL connected to  $V_{EE}$  for MLP16 and DIE only.
3. Specified with EN-SEL open for MLP16 and DIE only.
4. Specified with  $Q_{HG}/\bar{Q}_{HG}$  connected with 50 Ω to  $V_{CC} - 2V$  for MLP 8 only.

## 100K LVPECL DC Characteristics ( $V_{EE} = GND$ , $V_{CC} = +3.3V$ )

Symbol	Characteristic	-40°C		0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
$V_{OH}$	Output HIGH Voltage <sup>1,3</sup>	2255	2465	2305	2465	2305	2465	2305	2465	mV
$V_{OH}$	Output HIGH Voltage <sup>1,5</sup>	2215	2420	2275	2420	2275	2420	2275	2420	mV
$V_{OL}$	Output LOW Voltage <sup>1,3,5</sup>	1375	1745	1400	1655	1480	1680	1400	1680	mV
$V_{IH}$	Input HIGH Voltage									
	D/D, EN (PECL) <sup>1</sup> EN (CMOS/TTL)	2135 2000	2420 $V_{CC}$	2135 2000	2420 $V_{CC}$	2135 2000	2420 $V_{CC}$	2135 2000	2420 $V_{CC}$	mV
$V_{IL}$	Input LOW Voltage									
	D/D, EN (PECL) <sup>1</sup> EN (CMOS/TTL)	1490 GND	1825 800	1490 GND	1825 800	1490 GND	1825 800	1490 GND	1825 800	mV
$V_{BB}$	Reference Voltage <sup>1</sup>	1910	2050	1910	2050	1910	2050	1910	2050	mV
$I_{IL}$	Input LOW Current EN <sup>4</sup>	0.5		0.5		0.5		0.5		μA
$I_{IH}$	Input HIGH Current EN <sup>4</sup>		150		150		150		150	μA
$I_{EE}$	Power Supply Current <sup>2</sup>		48		48		48		54	mA

1. For supply voltages other than 3.3V, use the ECL table values and ADD supply voltage value.
2. Specified with  $V_{EEP}$  and CS-SEL open for MLP16 and DIE. Subtract 4mA for MLP8.
3. Specified with  $V_{EEP}$  and CS-SEL connected to  $V_{EE}$  for MLP16 and DIE only.
4. Specified with EN-SEL open for MLP16 and DIE only.
5. Specified with  $Q_{HG}/\bar{Q}_{HG}$  connected with 50 Ω to  $V_{CC} - 2V$  for MLP 8 only.

## 100K PECL DC Characteristics ( $V_{EE} = GND$ , $V_{CC} = +5.0V$ )

Symbol	Characteristic	-40°C		0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
$V_{OH}$	Output HIGH Voltage <sup>1,3</sup>	3955	4165	4005	4165	4005	4165	4005	4165	mV
$V_{OH}$	Output HIGH Voltage <sup>1,5</sup>	3915	4120	3975	4120	3975	4120	3975	4120	mV
$V_{OL}$	Output LOW Voltage <sup>1,3,5</sup>	3075	3445	3100	3338	3100	3338	3100	3338	mV
$V_{IH}$	Input HIGH Voltage									
	D/D, EN (PECL) <sup>1</sup> EN (CMOS/TTL)	3835 2000	4120 $V_{CC}$	3835 2000	4120 $V_{CC}$	3835 2000	4120 $V_{CC}$	3835 2000	4120 $V_{CC}$	mV
$V_{IL}$	Input LOW Voltage									
	D/D, EN (PECL) <sup>1</sup> EN (CMOS/TTL)	3190 GND	3525 800	3190 GND	3525 800	3190 GND	3525 800	3190 GND	3525 800	mV
$V_{BB}$	Reference Voltage <sup>1</sup>	3610	3750	3610	3750	3610	3750	3610	3750	mV
$I_{IL}$	Input LOW Current EN <sup>4</sup>	0.5		0.5		0.5		0.5		μA
$I_{IH}$	Input HIGH Current EN <sup>4</sup>		150		150		150		150	μA
$I_{EE}$	Power Supply Current <sup>2</sup>		48		48		48		54	mA

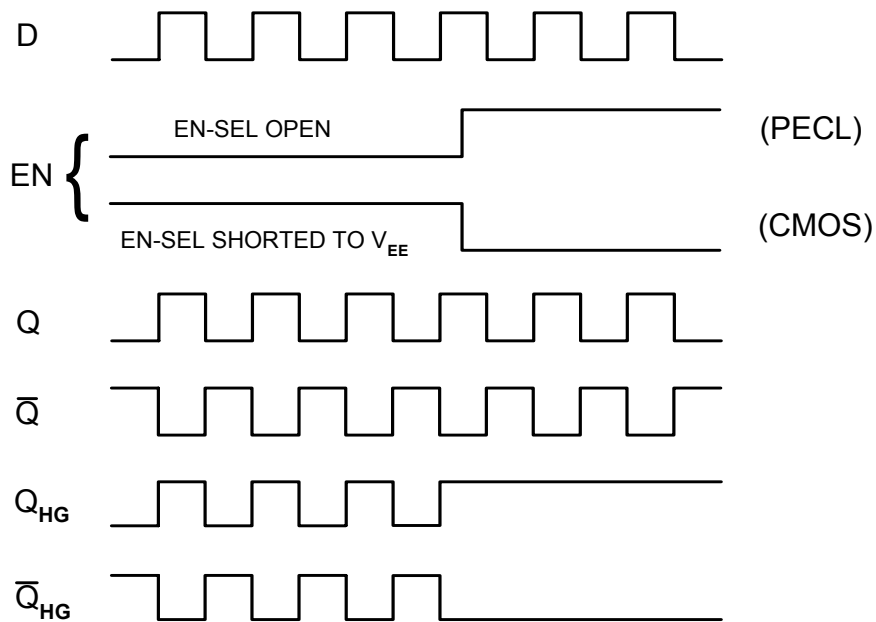
1. For supply voltages other than 5.0V, use the ECL table values and ADD supply voltage value.
2. Specified with  $V_{EEP}$  and CS-SEL open for MLP16 and DIE. Subtract 4mA for MLP8.
3. Specified with  $V_{EEP}$  and CS-SEL connected to  $V_{EE}$  for MLP16 and DIE only.
4. Specified with EN-SEL open for MLP16 and DIE only.
5. Specified with  $Q_{HG}/\bar{Q}_{HG}$  connected with 50 Ω to  $V_{CC} - 2V$  for MLP 8 only.

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## AC Characteristics ( $V_{EE} = -3.0V$ to $-5.5V$ ; $V_{CC} = GND$ or $V_{EE} = GND$ ; $V_{CC} = +3.0V$ to $+5.5V$ )

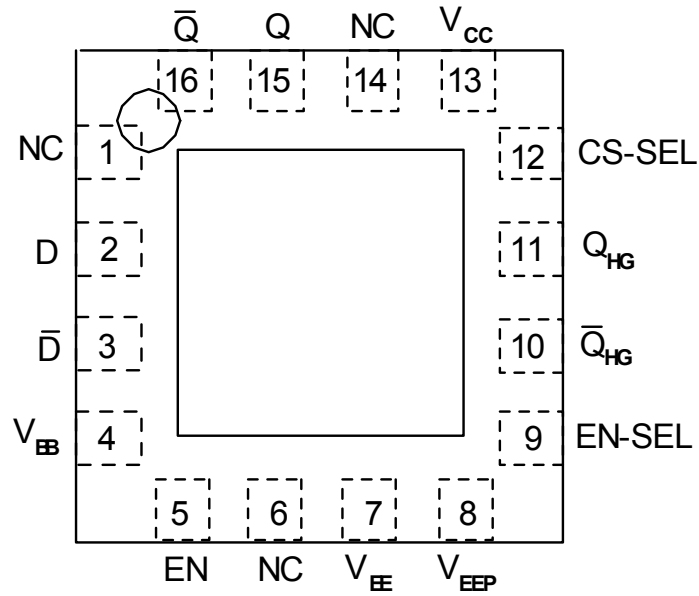
Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$t_{PLH} / t_{PHL}$	Propagation Delay D to Q/ $\bar{Q}$ Outputs <sup>1</sup> (SE) D to $Q_{HG}/\bar{Q}_{HG}$ Outputs <sup>1</sup> (SE)			400 550			400 550			400 550			430 630	ps
$t_{SKEW}$	Duty Cycle Skew <sup>2</sup> (SE)		5	20		5	20		5	20		5	20	ps
$V_{PP}$	Minimum Input Swing <sup>3</sup> DIFF SE	80 160			80 160			80 160			80 160			mV
$t_r / t_f$	Output Rise/Fall Times <sup>1</sup> (20% - 80%)	100		260	100		260	100		260	100		260	ps

- For MLP16 output specified with  $V_{EEP}$  and CS-SEL connected to  $V_{EE}$  with an AC coupled  $50\Omega$  load. For MLP8, AC coupled  $50\Omega$  on  $\bar{Q}$  to  $V_{CC} - 2V$  and DC coupled  $50\Omega$  to  $V_{CC} - 2V$  on  $Q_{HG}/\bar{Q}_{HG}$ .
- Duty cycle skew is the difference between a  $t_{PLH}$  and  $t_{PHL}$  propagation delay through a device.
- $V_{PP}$  is the minimum peak-to-peak input swing for which AC parameters guaranteed. The device has a voltage gain of  $\approx 20$  to Q/ $\bar{Q}$  outputs and a voltage gain of  $\approx 100$  to  $Q_{HG}/\bar{Q}_{HG}$  outputs.



TIMING DIAGRAM

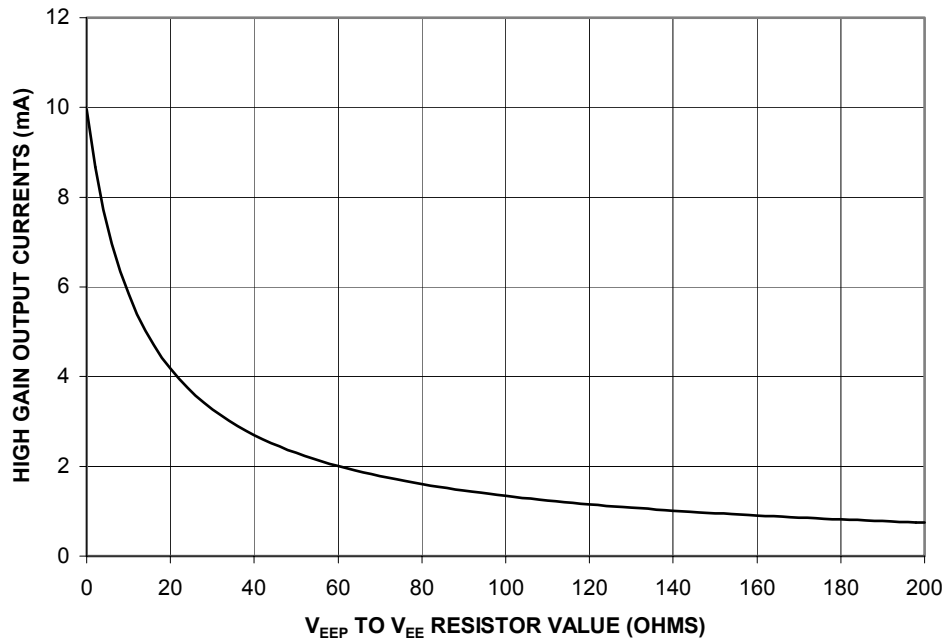
MLP 16  
3x3 mm



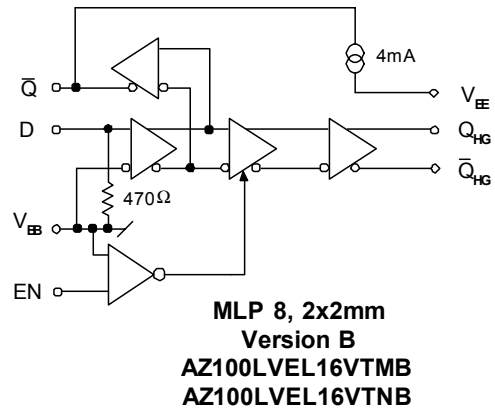
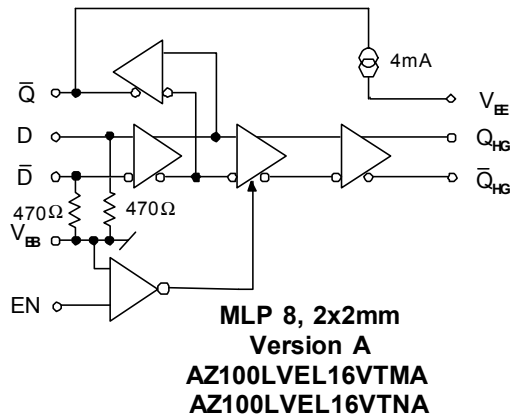
TOP VIEW

Bottom Center Pad may be left open or tied to  $V_{EE}$

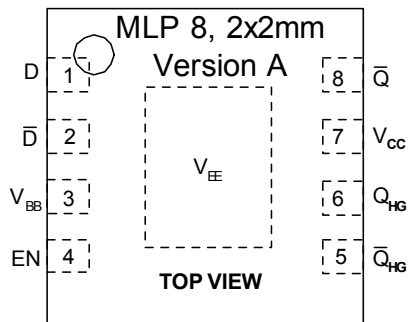
ADJUSTABLE HIGH GAIN OUTPUT CURRENT



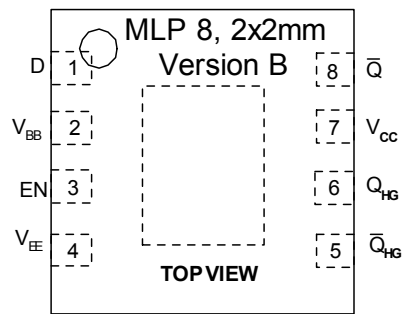
**LOGIC DIAGRAMS AND PINOUTS FOR  
2x2mm PACKAGE**



**EN operation on the versions A and B follows the PECL functionality, see Timing Diagram above.**



**Bottom Center Pad is the  $V_{EE}$  return.**

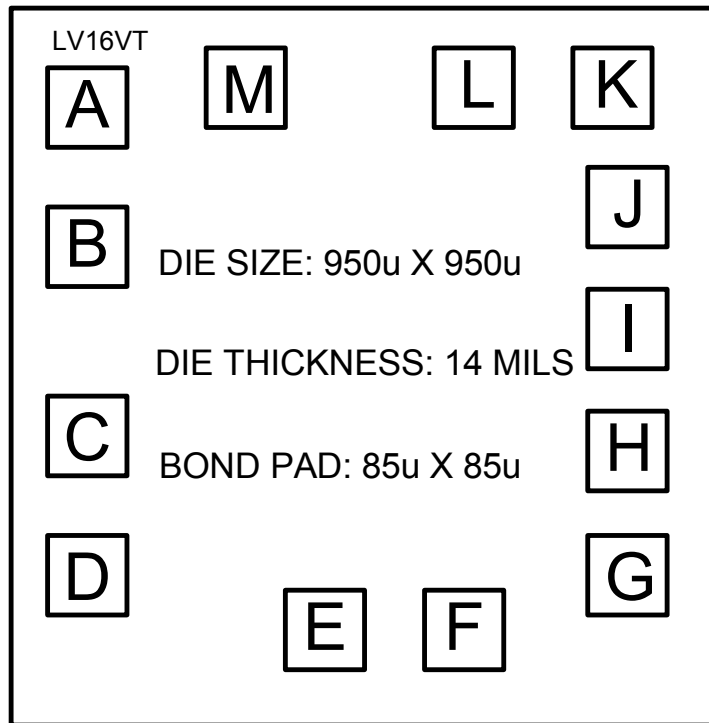


**Bottom Center Pad may be left open or tied to  $V_{EE}$ . Pin 4 is the  $V_{EE}$  return.**

AZ100LVEL16VT

DIE PAD COORDINATES

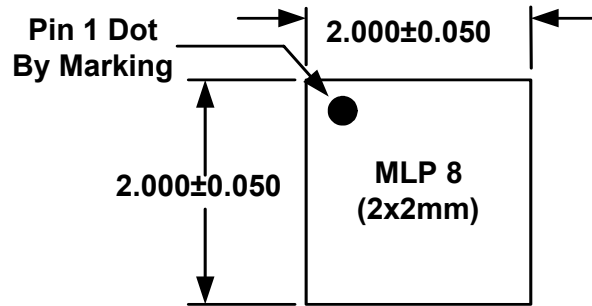
AZ100LVEL16VT DIE:



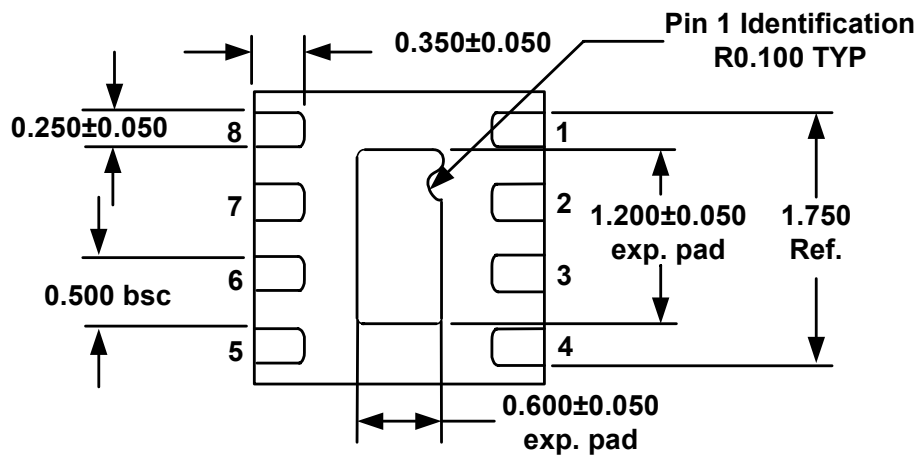
PAD CENTER COORDINATES

NAME	PAD DESIGNATION	X(Microns)	Y(Microns)
A	D	-342.5	312.5
B	$\bar{D}$	-342.5	144.5
C	$V_{BB}$	-342.5	-87.0
D	EN	-342.5	-255.0
E	$V_{EE}$	-33.5	-312.5
F	$V_{EEP}$	126.5	-312.5
G	EN-SEL	312.5	-248.5
H	$\bar{Q}_{HG}$	312.5	-98.5
I	$Q_{HG}$	312.5	51.5
J	CS-SEL	312.5	201.5
K	$V_{CC}$	302.5	342.5
L	Q	142.5	342.5
M	$\bar{Q}$	-140.5	342.5

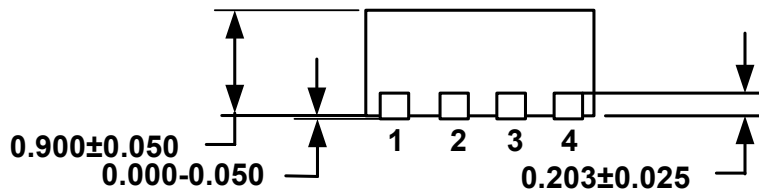
**PACKAGE DIAGRAM**  
**MLP 8 DUAL 2x2mm**



TOP VIEW



BOTTOM VIEW

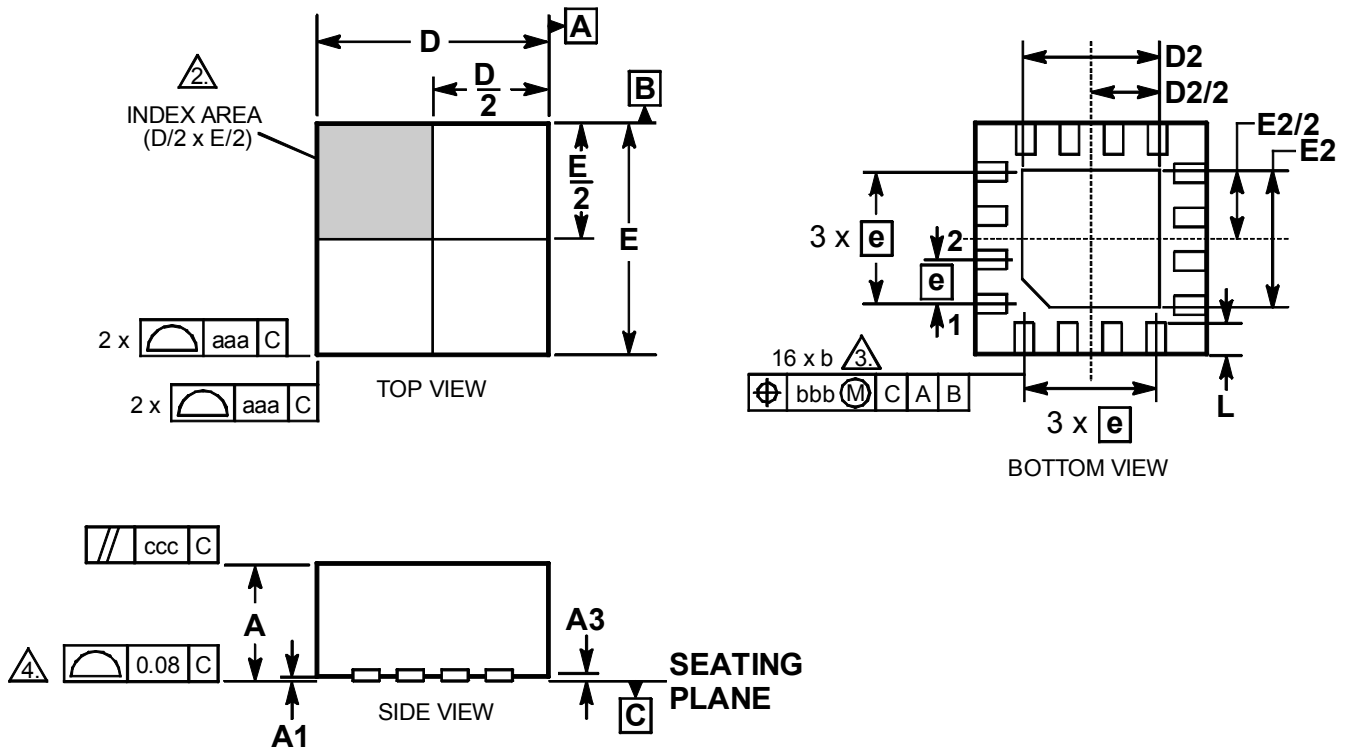


SIDE VIEW

**Note: All dimensions are in mm**



**PACKAGE DIAGRAM  
MLP 16**



**NOTES:**

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME T14-1994.
- $\triangle 2$ . THE TERMINAL #1 AND PAD NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012.
- $\triangle 3$ . DIMENSION  $b$  APPLIES TO METALLIZED PAD AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM THE PAD TIP.
- $\triangle 4$ . COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS

DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05□
A3	0.25 REF	
b	0.18	0.30
D	2.90	3.10□
D2	0.25	1.95□
E	2.90	3.10□
E2	0.25	1.95□
e	0.50 BSC	
L	0.30	0.50
aaa	0.25	
bbb	0.10	
ccc	0.10	

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